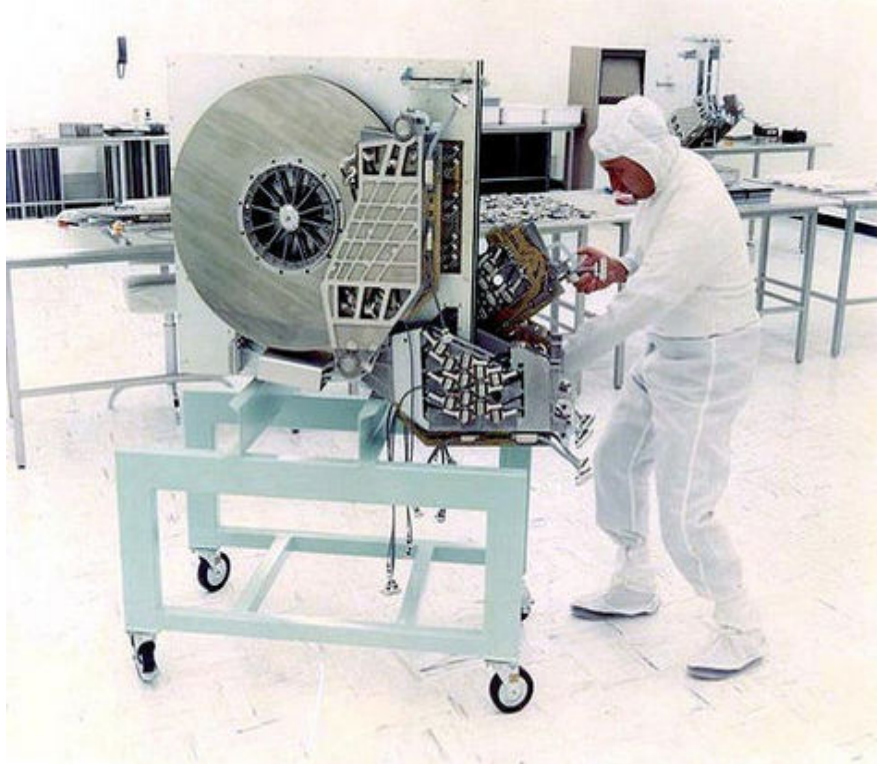




# Polarized neutron reflectivity for the exploration of magnetic nanostructures.

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*Instituut voor Kern- en Stralingsfysica*  
*KU Leuven, Belgium*

# Size does matter! Ex.: hard disk



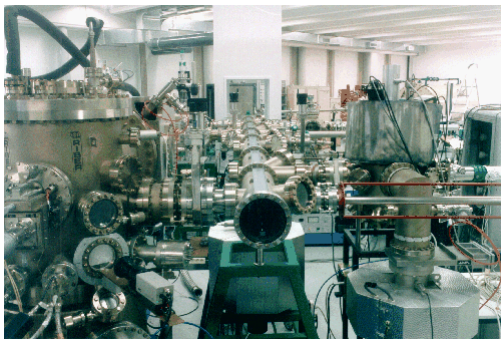
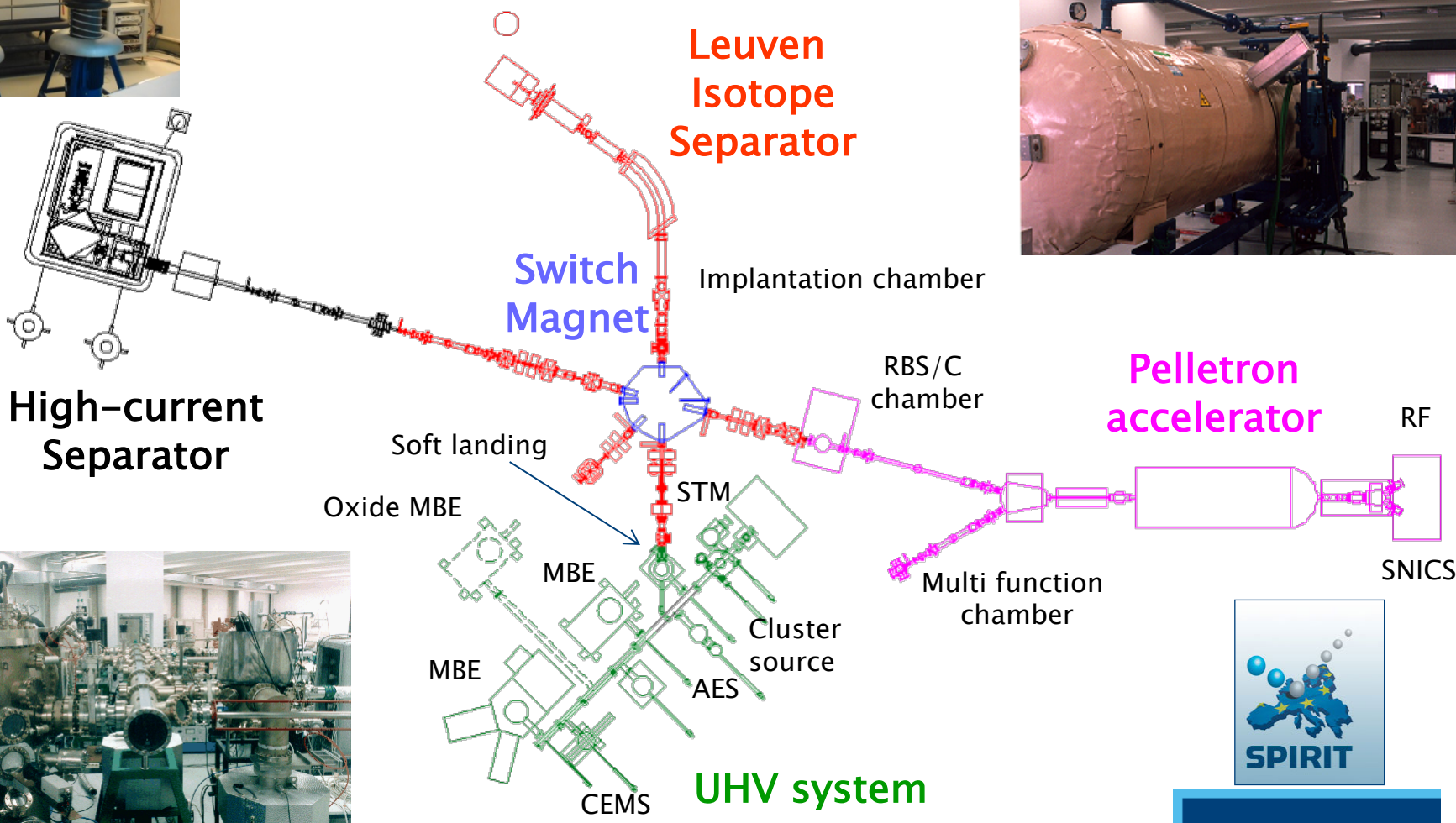
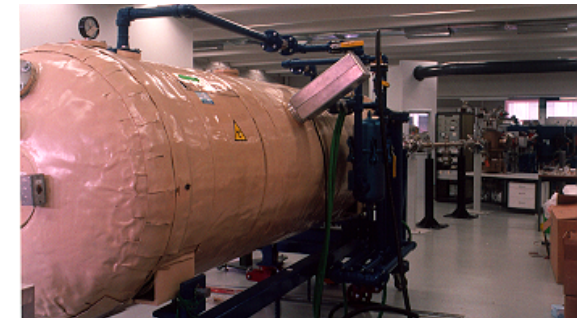
Anno 1975



Anno 2017

**Progress is strongly rooted in fundamental studies of nanomagnetism, interfacial effects and dynamics!**

# Ion and Molecular Beam Laboratory



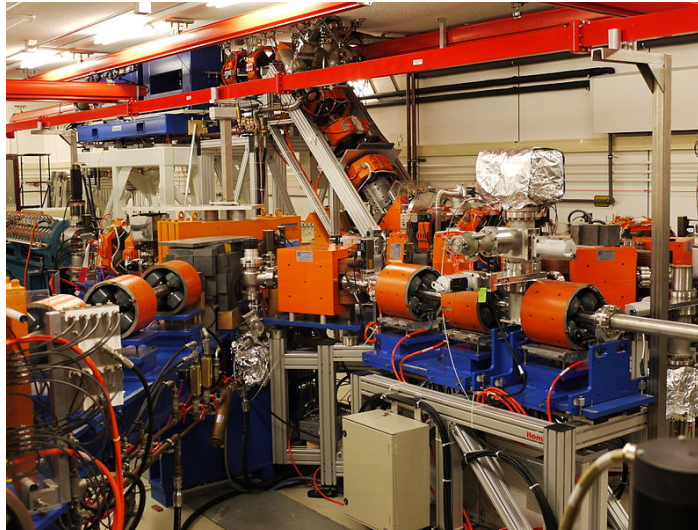


# Complementarity with LSF

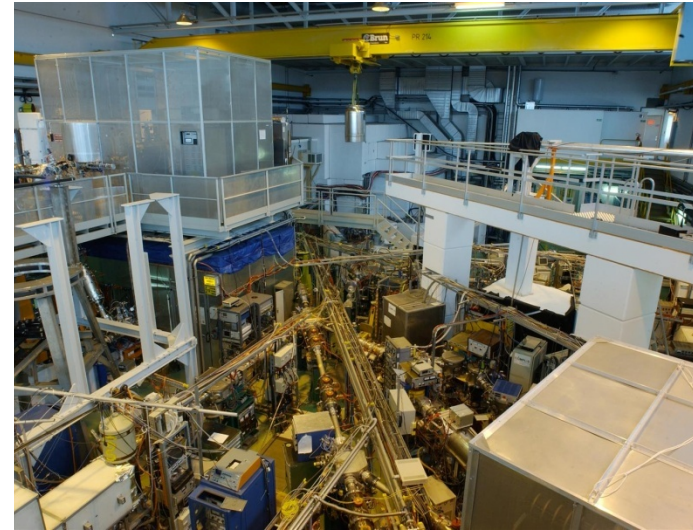
Complementary approach :  
experiments at international large-scale facilities  
for neutrons, muons, photons and radioactive ions



*ESRF and ILL,  
Grenoble*



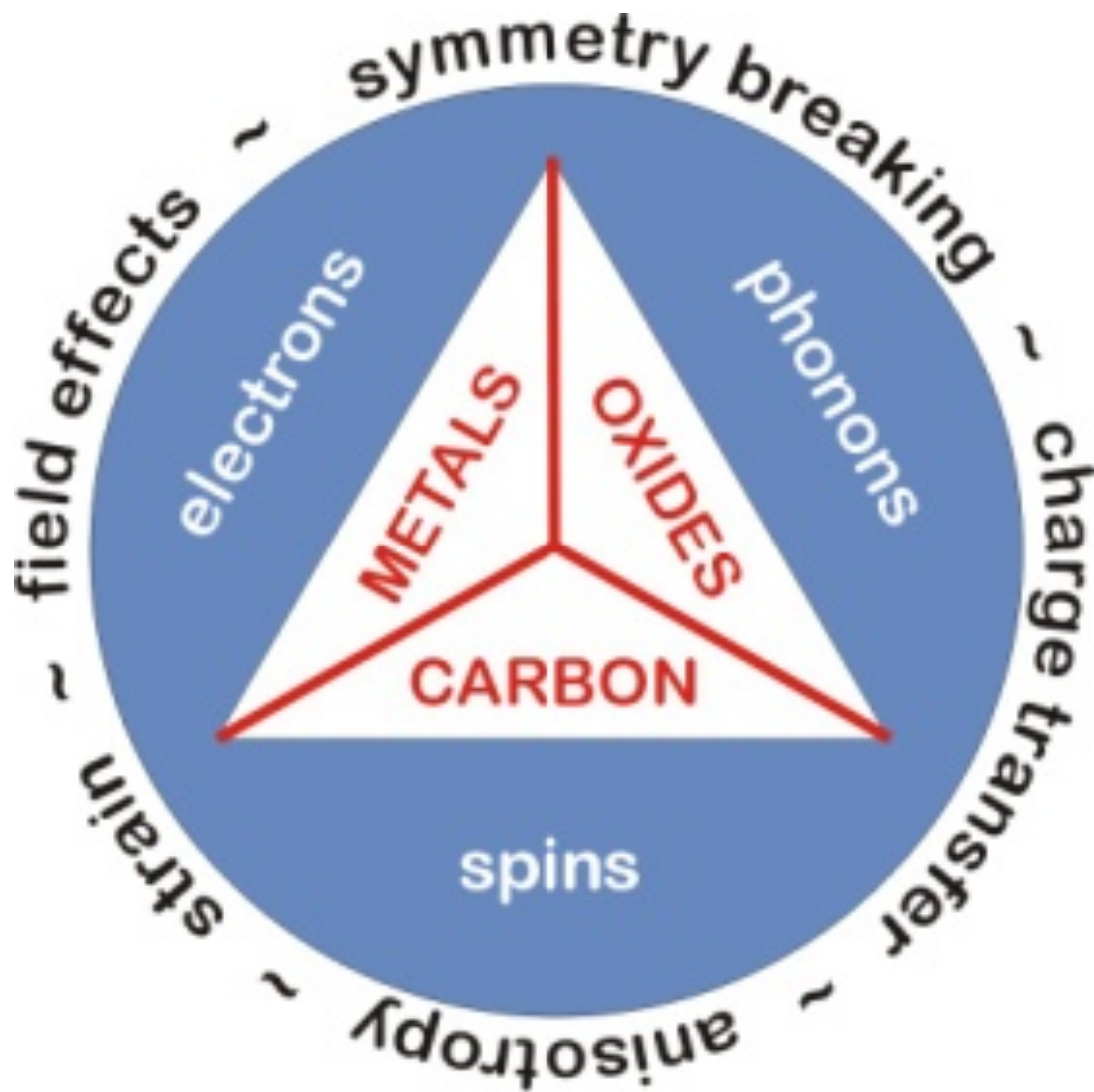
*FELIX  
Nijmegen*



*ISOLDE, CERN*

*MLZ (Munich), HZB (Berlin), PSI (Villigen), DESY-Petra (Hamburg),  
BESSY (Berlin), APS (Argonne)...*





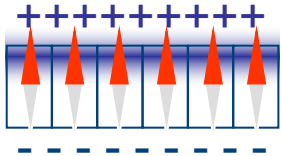
# General framework and trends

➔ **interface-driven effects** in ‘hybrid’ magnetic structures

## Confrontation of different order parameters



ferromagnet/antiferromagnet (exchange bias)  
strong/weak anisotropy (exchange spring)  
ferroelectric/ferromagnet (‘composite’ multiferroic)  
superconductor/ferromagnet (proximity effect)  
dilute magnetic semiconductor/ferromagnet  
topological insulator/ferromagnet



...

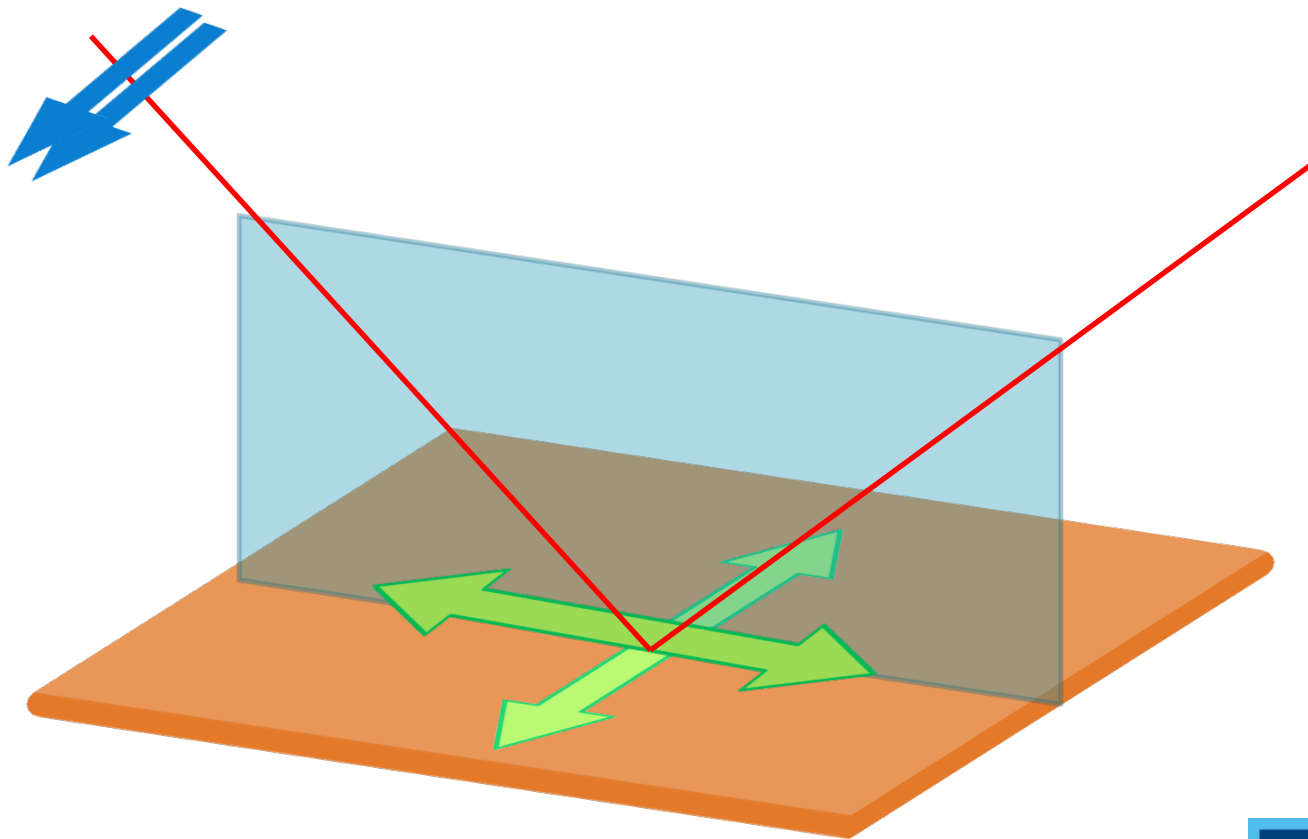


➔ resolve interaction at relevant length scale  
correlate with structure/chemistry of interface

**Fundamental research but close link to applications!**

# PNR: two fundamental interactions

Non Spin Flip Interaction:  
Neutron spin  $\perp$  magnetization



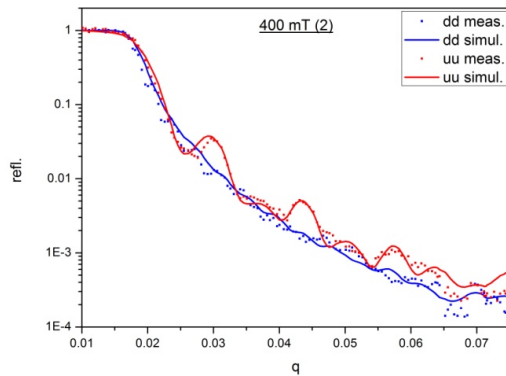
PNR: key to asymmetry in reversal mechanism in EB systems

M.R. Fitzsimmons, P. Yashar, C. Leighton, I.K. Schuller, J. Nogués, C.F. Majkrzak, J.A. Dura,

PRL **84**, 3986 (2000); F. Radu et al., PRB **67**, 134409 (2003)

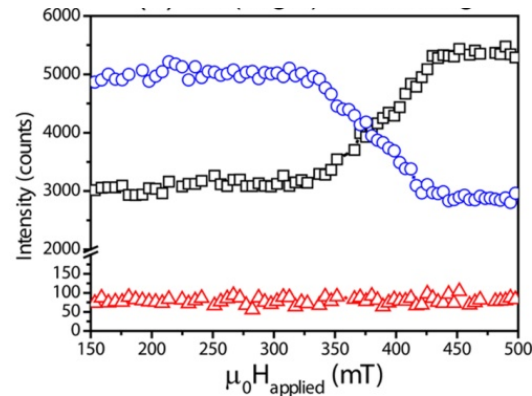


# Polarized neutron reflectivity (PNR)



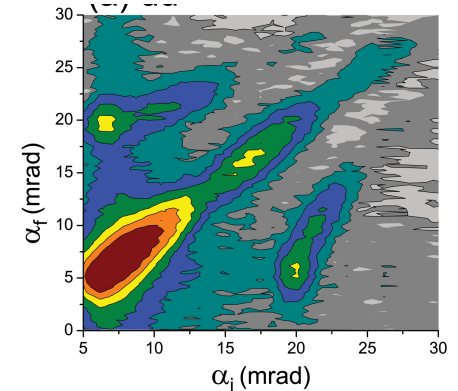
**Specular reflectivity scan at fixed field**

**Magnetic depth profile**



**Magnetic field scan at fixed angle**

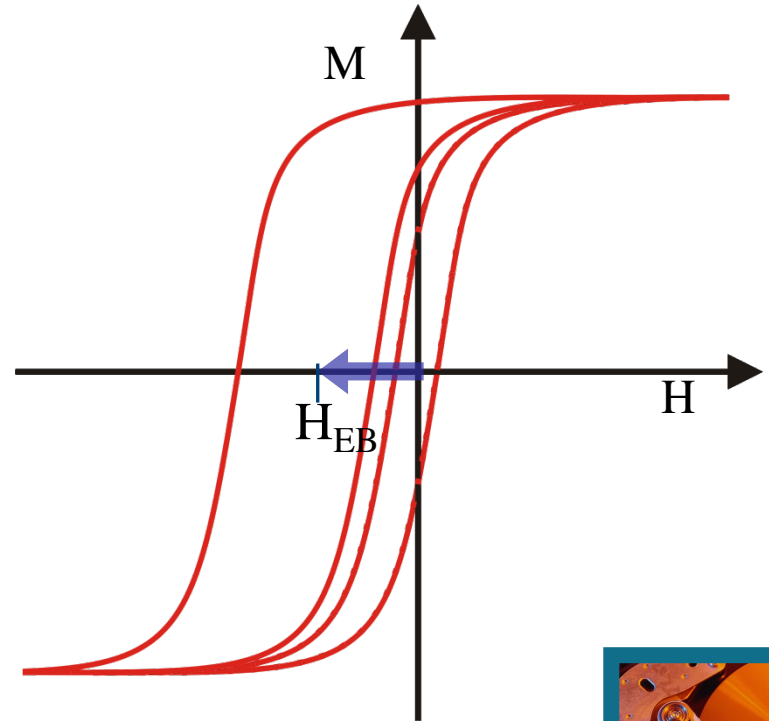
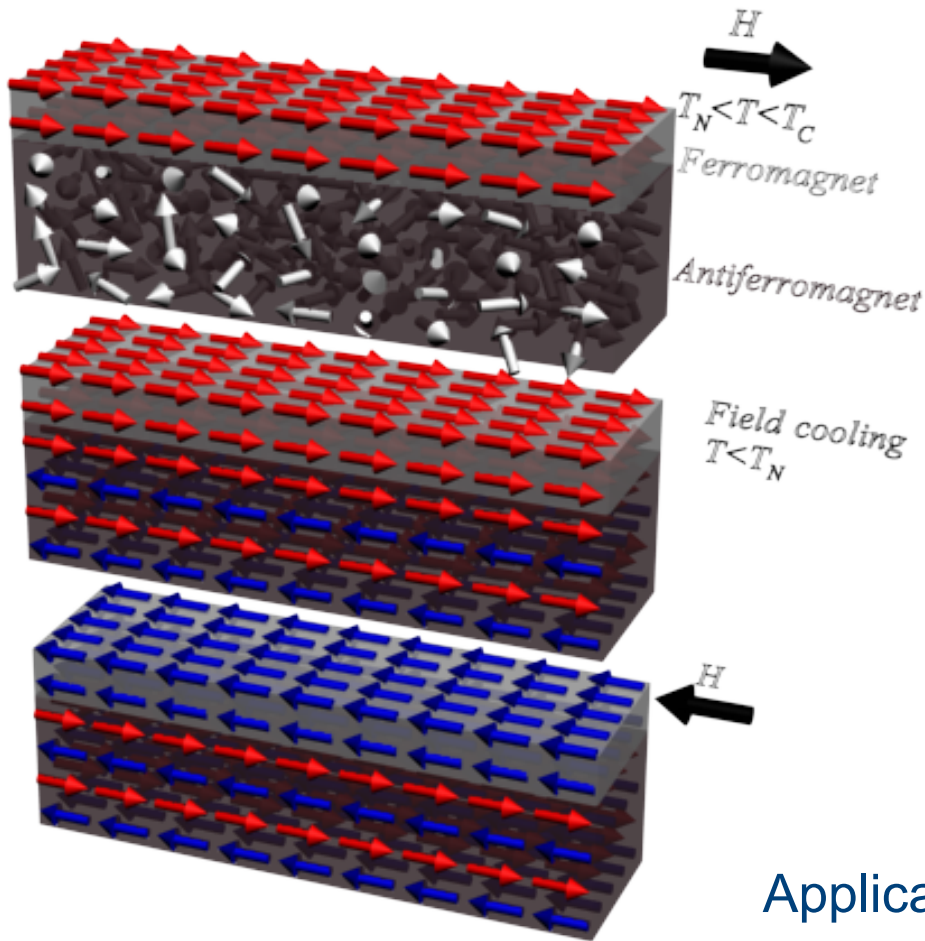
**Magnetic reversal mechanism**



**Reciprocal space map at fixed field**

**In-plane magnetic correlations**

# Exchange bias effect



Application: spin valve, sensors...

W. H. Meiklejohn and C. P. Bean, Phys. Rev. **102**, 1413 (1956)

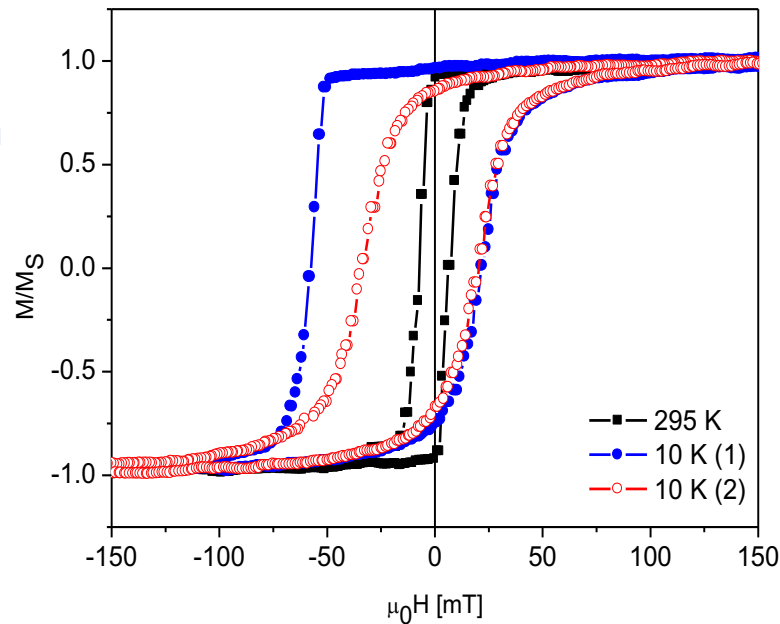
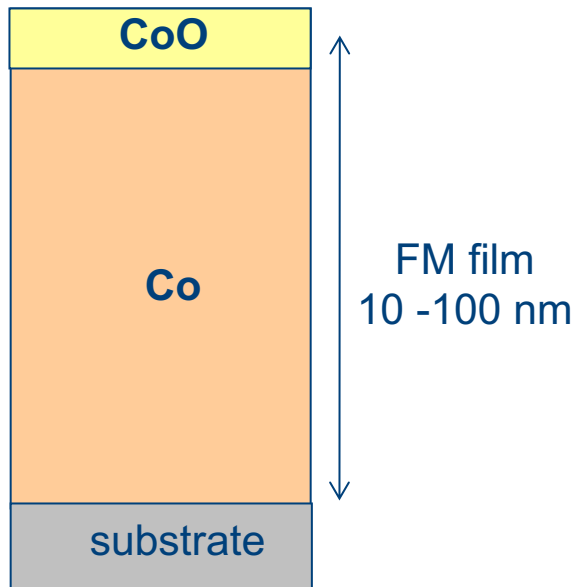
J. Nogués and Ivan K. Schuller, JMMM 192 (1999)

F. Radu and H. Zabel, Springer Tracts Mod. Phys. 227 1743 (2007)

# Exchange Bias in thin films

## Bilayer exchange bias system:

- Archetypal EB system: **Co-CoO** bilayers
- CoO limited to 2-3 nm due to **self-limiting** nature of oxidation

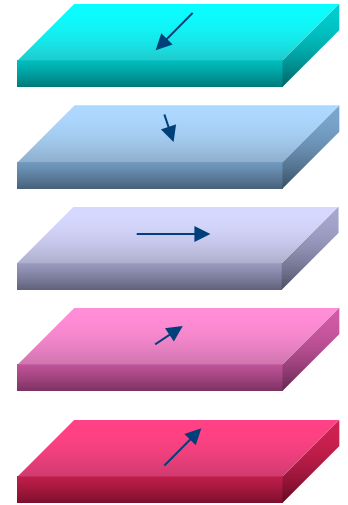
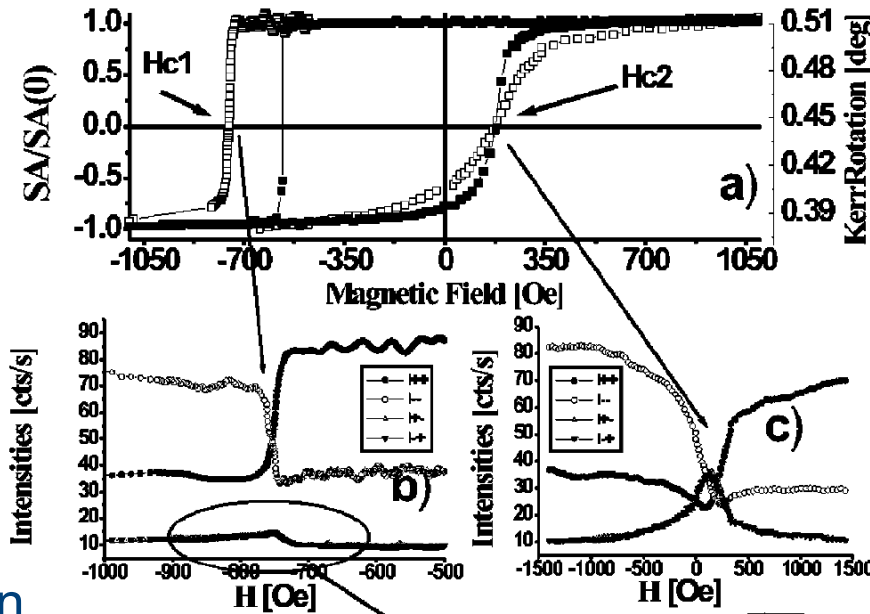
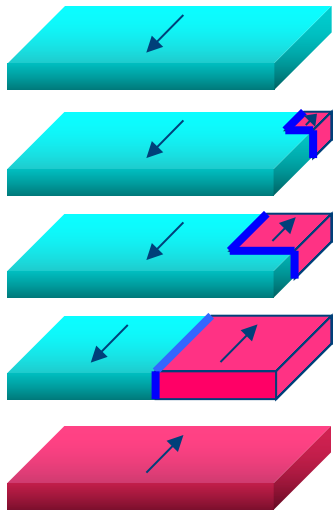


$H_E$  = shift  
 $H_C$  = broadening



# Asymmetry in reversal

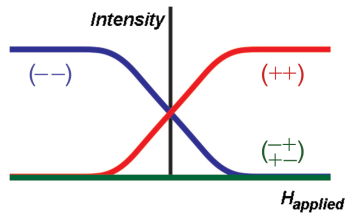
Asymmetry between 1<sup>st</sup> (domain wall nucleation and motion) and 2<sup>nd</sup> (coherent rotation) magnetization reversals by magnetic field scans in PNR



Rotation

Domain wall motion

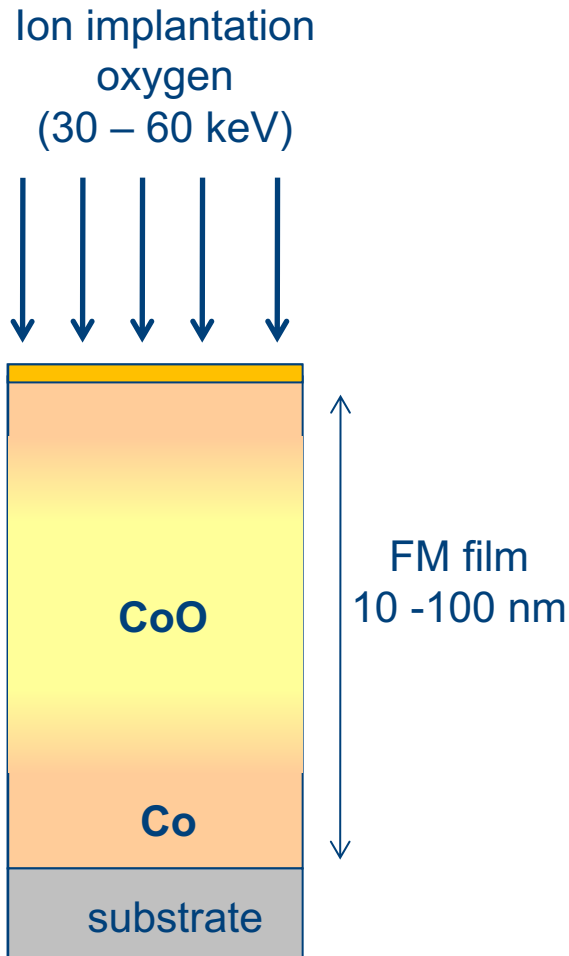
Nucleation and domain wall movement



Coherent rotation



# Exchange Bias by ion implantation

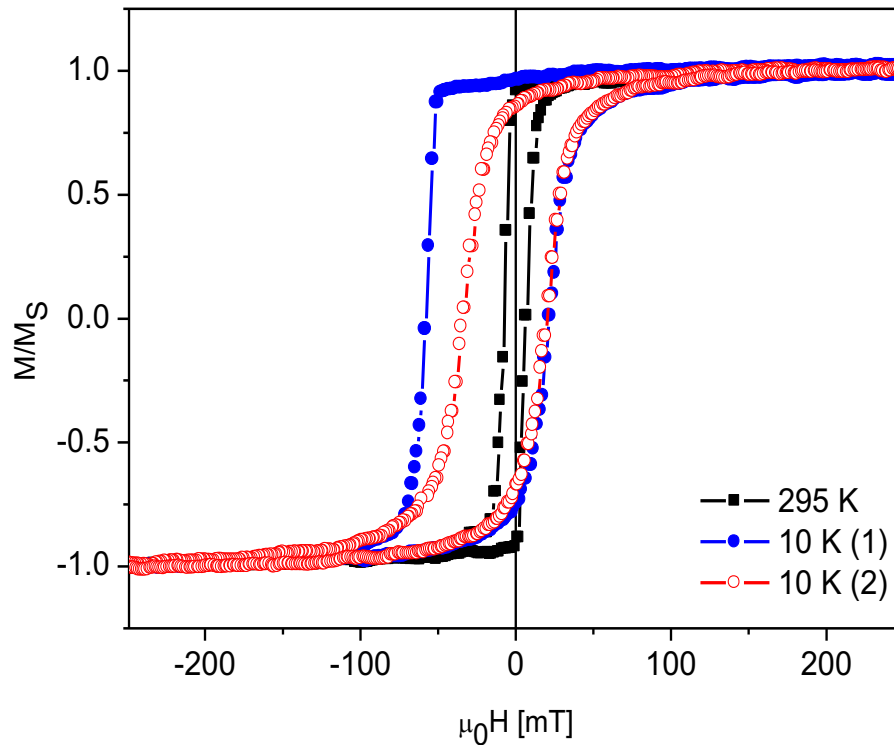


## Implanted exchange bias system:

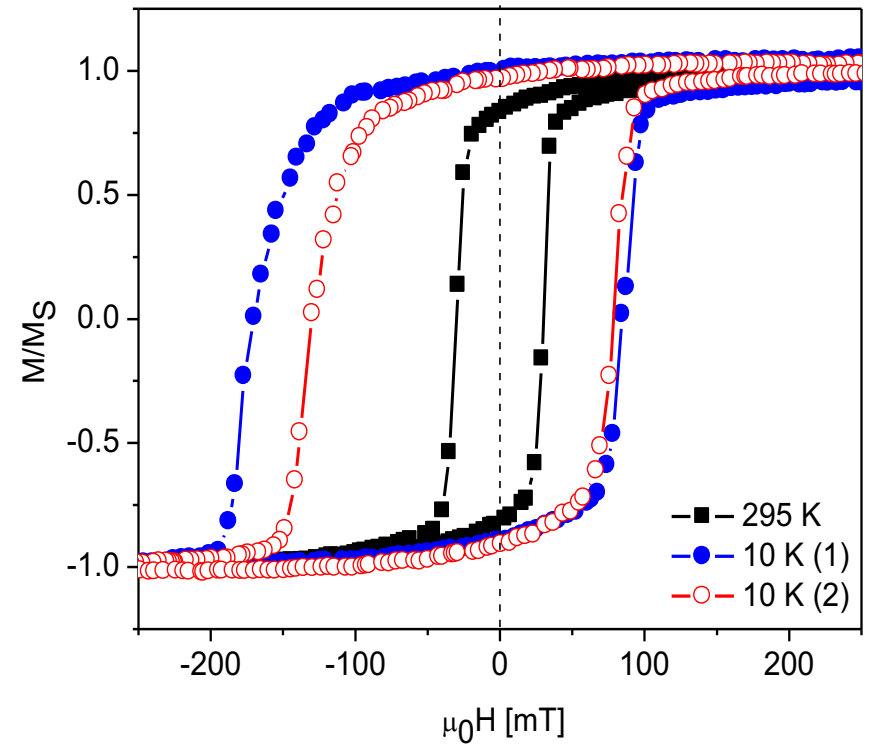
- **Overcome limited thickness** of surface oxidation
- **AFM embedded** in FM
- Up to 14 % O in Co
- Multiple **interfaces** between FM and AFM

**Challenge:** correlate magnetism with gradient in thin film, small area sample

# EB by ion implantation vs. bilayer



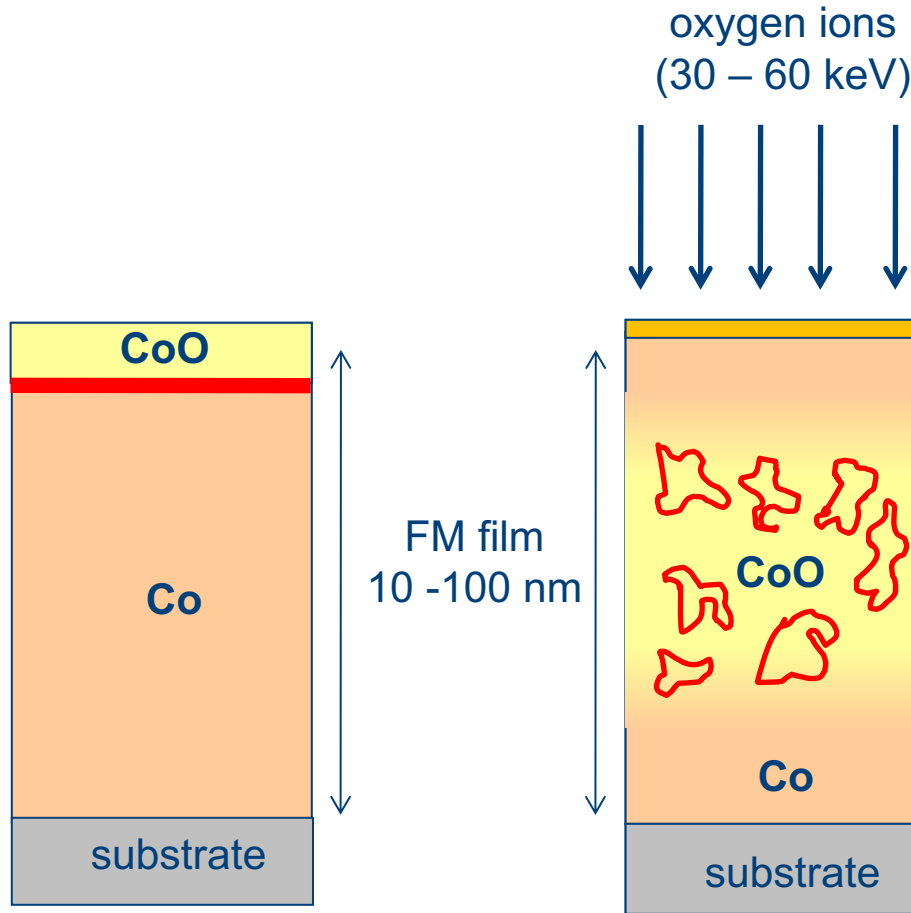
**Bilayer system**  
30 nm Co film  
surface oxidation



**Implanted system**  
100 nm Co film  
 $1 \times 10^{17}$   $^{16}\text{O}$  at 60 keV



# FM/AFM interface

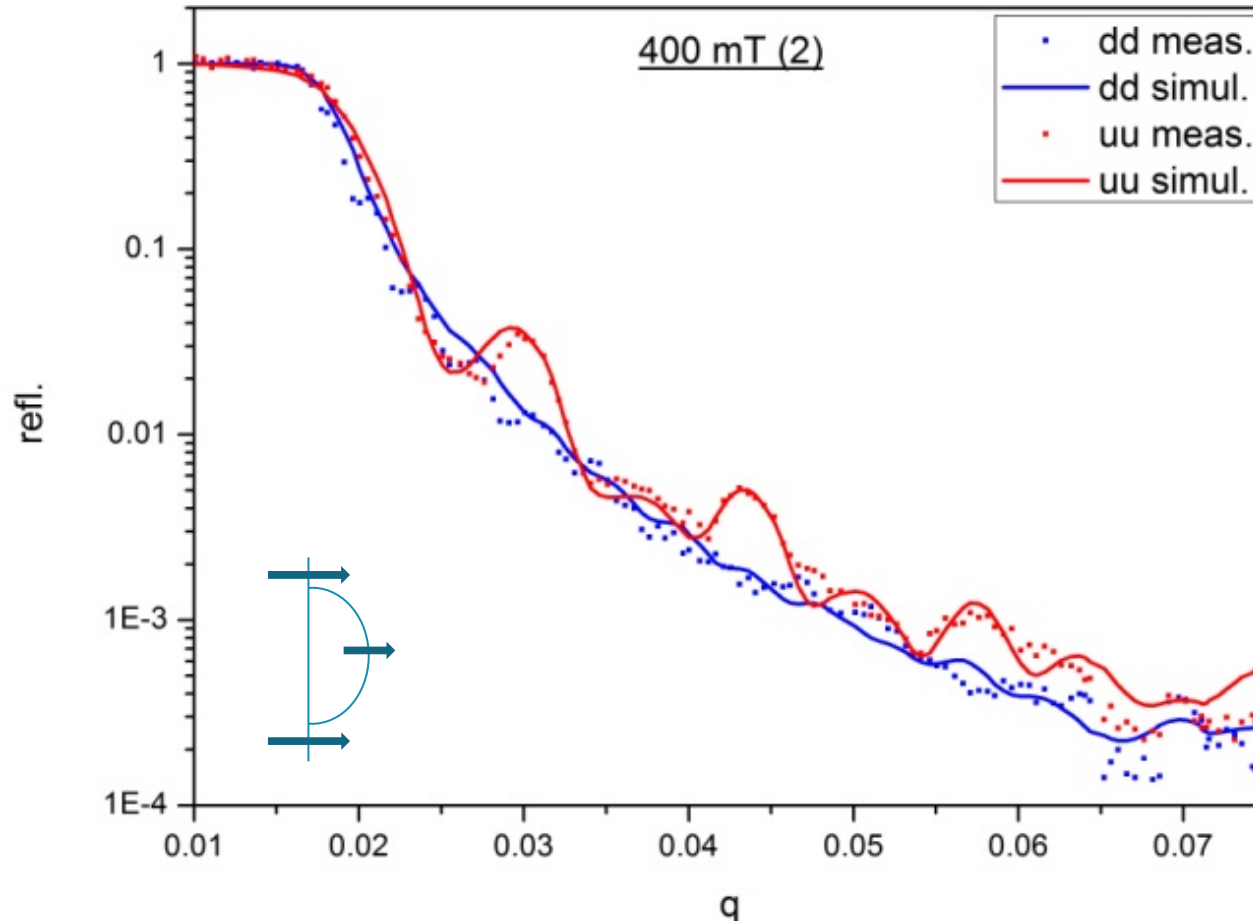


**Bilayer system:** planar interface between FM and AFM

**Implanted system:** interface between FM and AFM distributed throughout layer

- magnetic depth profile? reversal mechanism ?
- probe by polarized neutron reflectivity

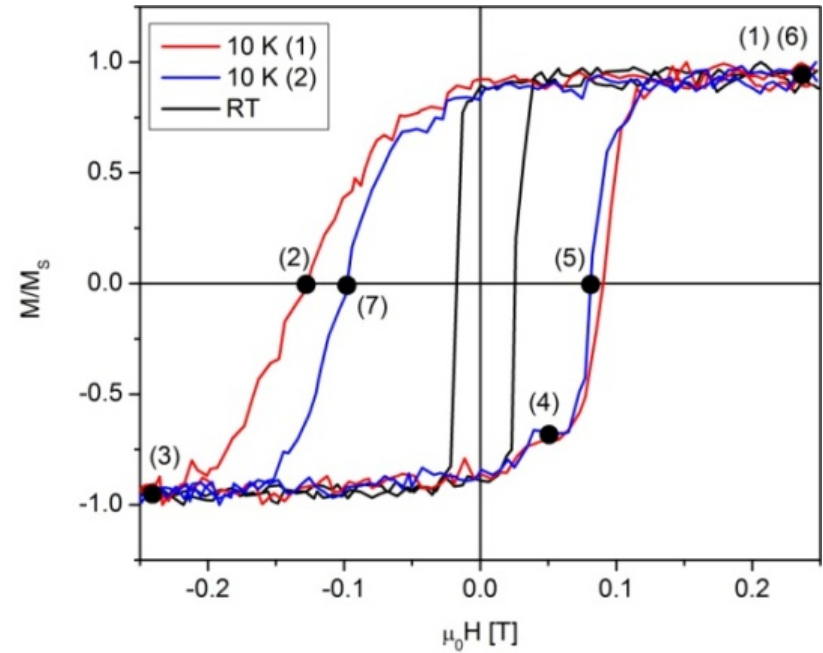
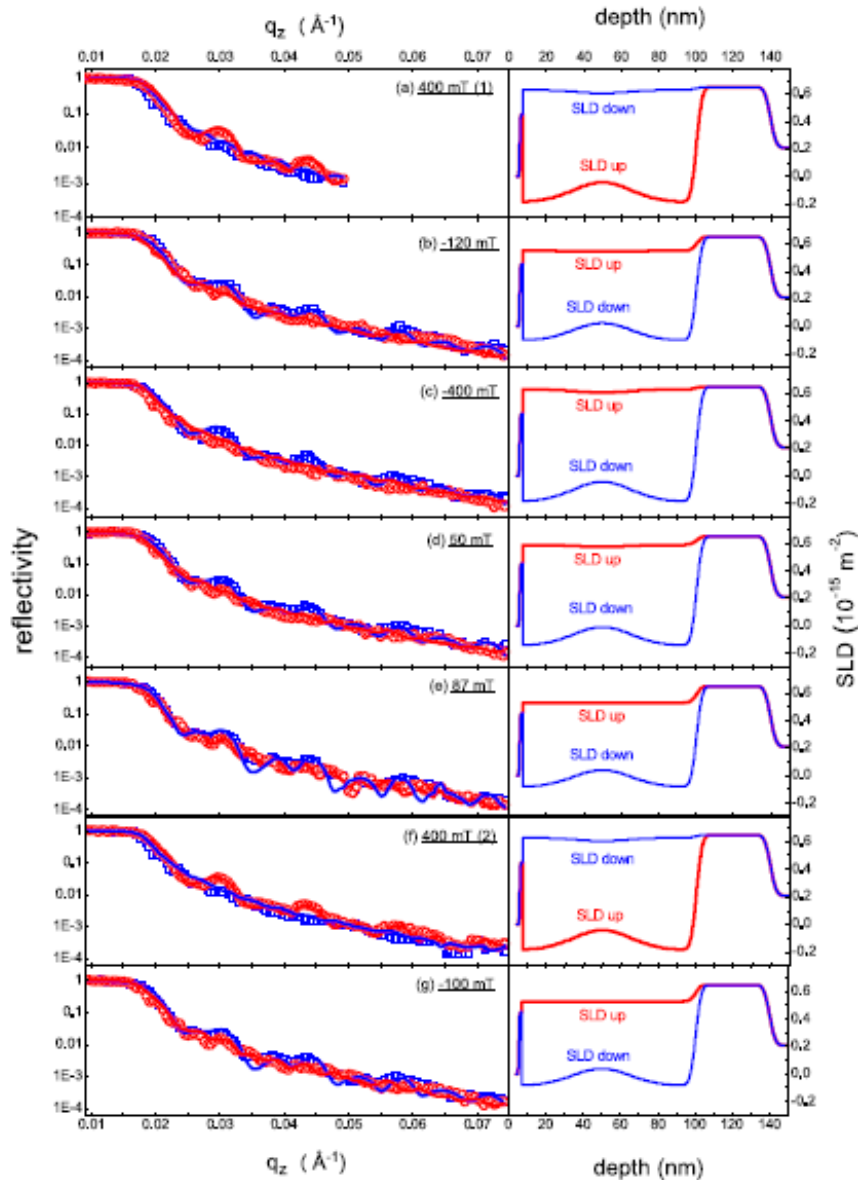
# Magnetic depth profile



## Polarized neutron reflectivity:

- chemical depth profile (like XRR) *plus*
- magnetic depth profile (vectorial)

# Magnetic depth profile

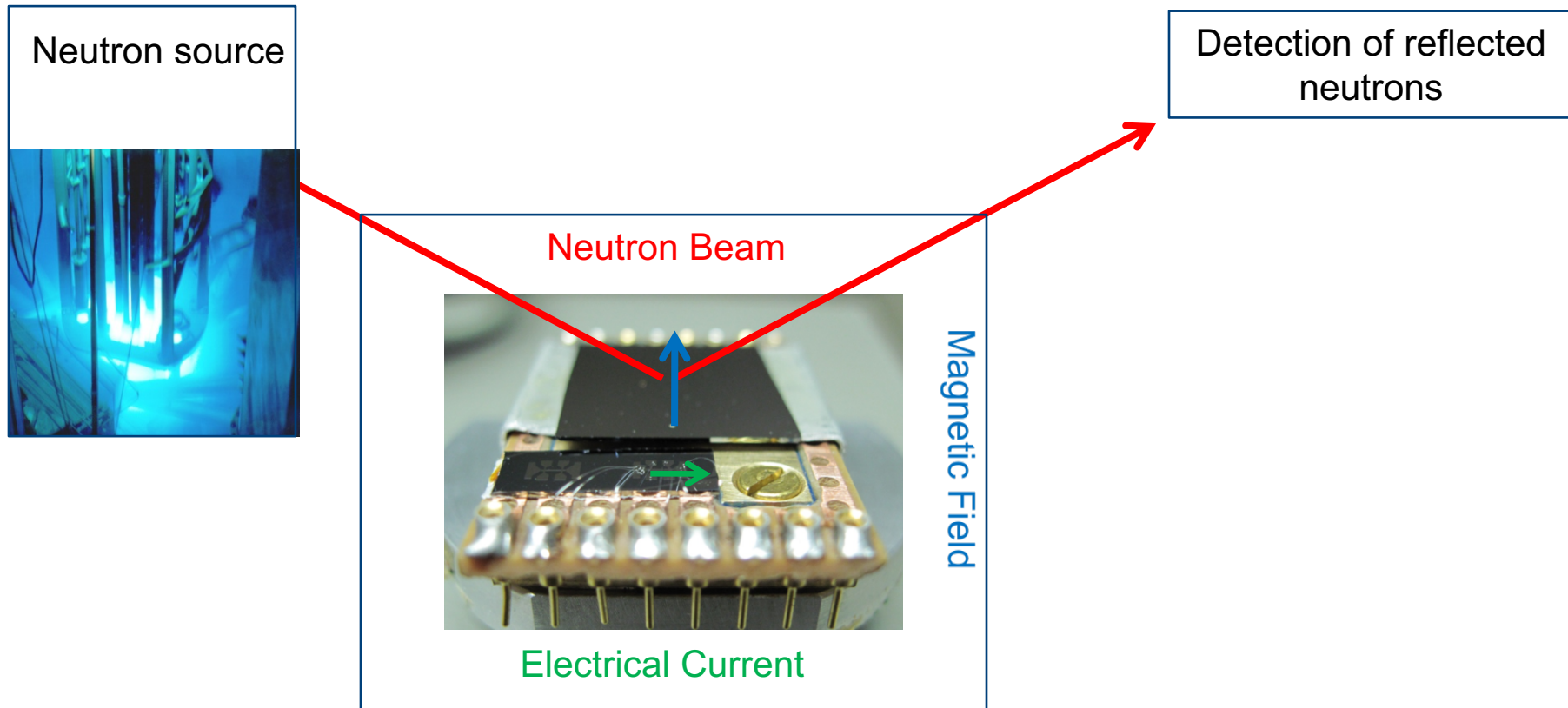


**Magnetic depth profile  
correlates well with  
gaussian implantation  
profile**



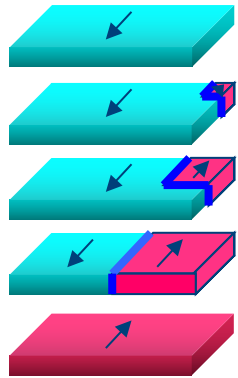
# Best of both worlds: PNR and AMR

Simultaneous measurement of  
PNR and AMR in reflectometer



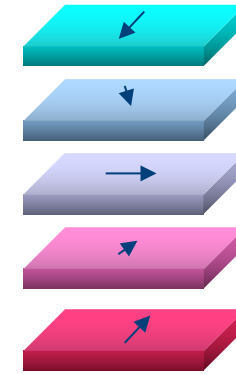
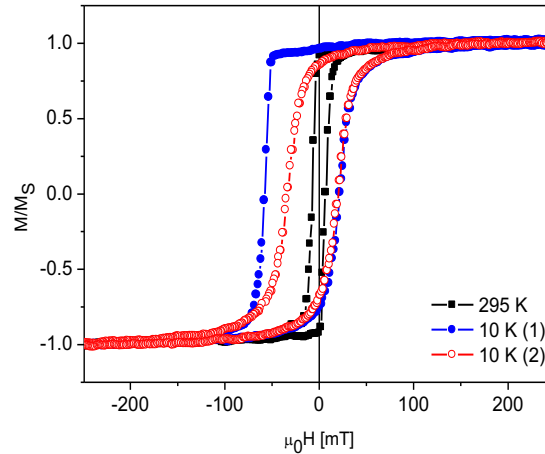
Combination PNR-AMR solves several experimental issues !

# Magnetization reversal mechanism

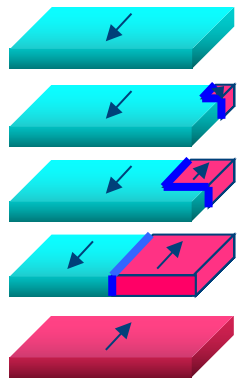


Domain wall motion

## BILAYER

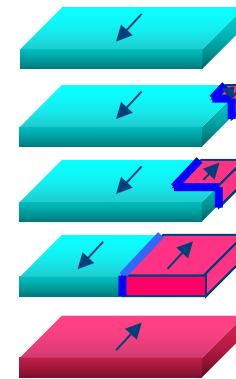
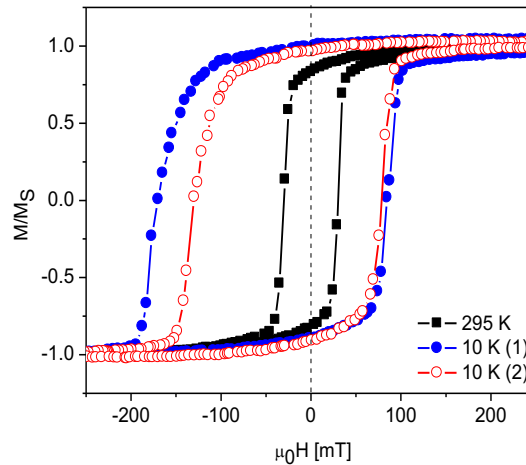


Rotation



Domain wall motion

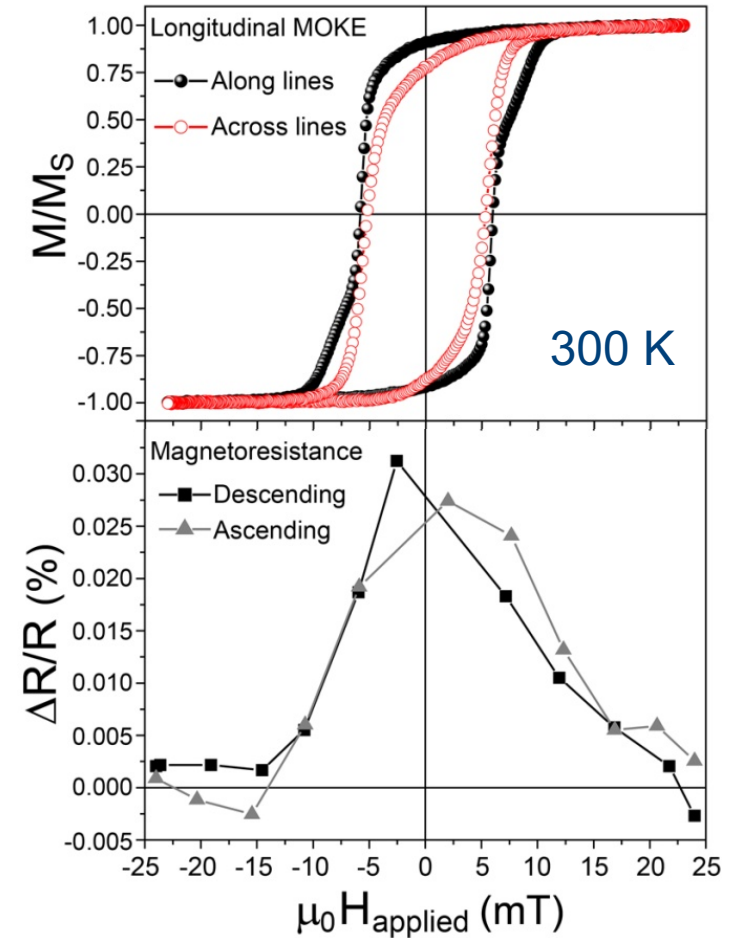
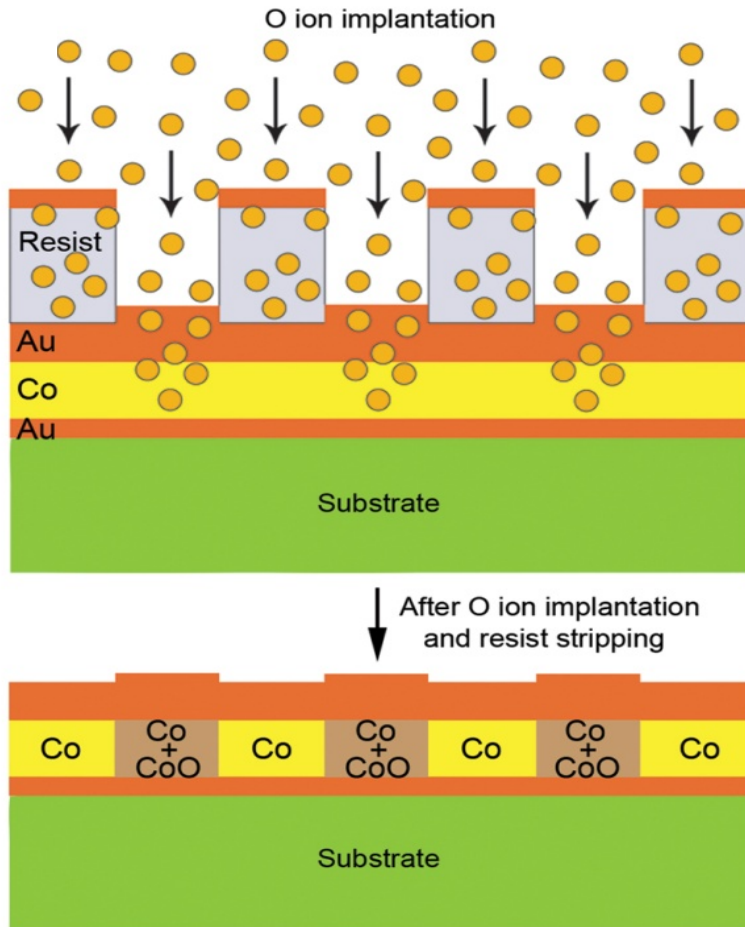
## IMPLANTED SYSTEM



Domain wall motion

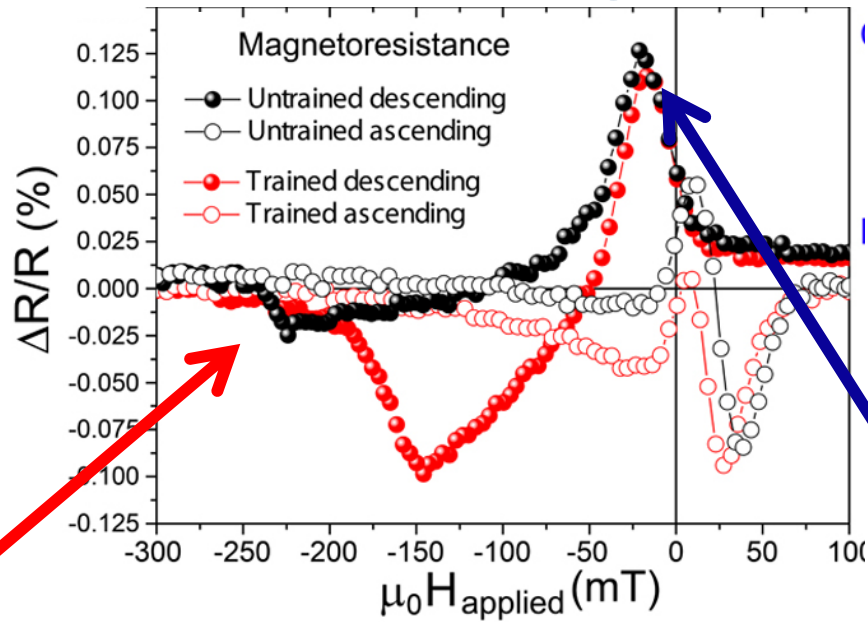
# Lateral patterns in 30 nm Co film

Combine ion implantation with UV-lithography



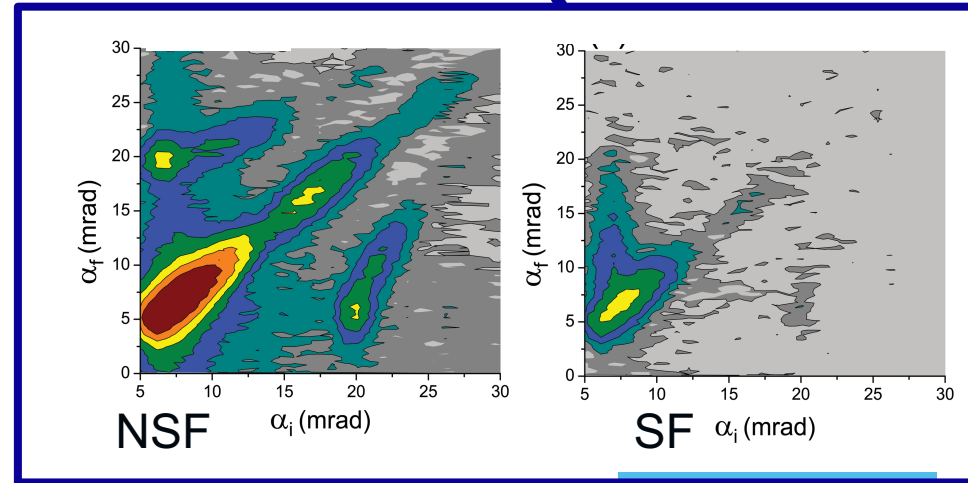
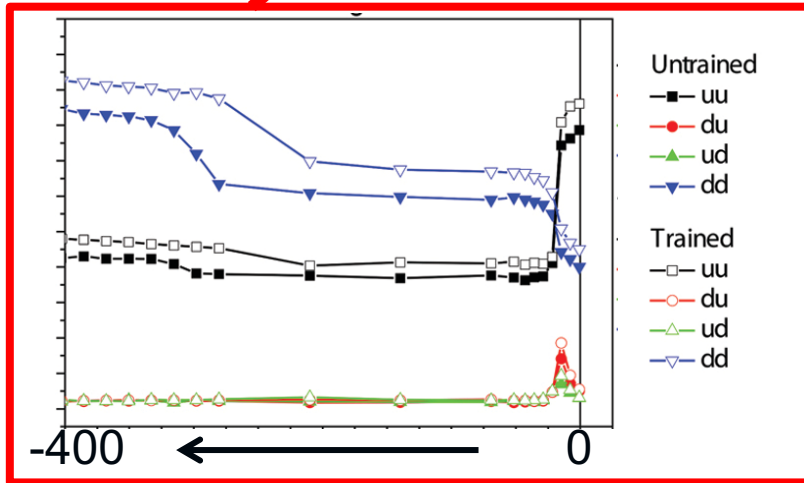
Magnetoresistance at room temperature: GMR mechanism

# Low temperature magnetoresistance



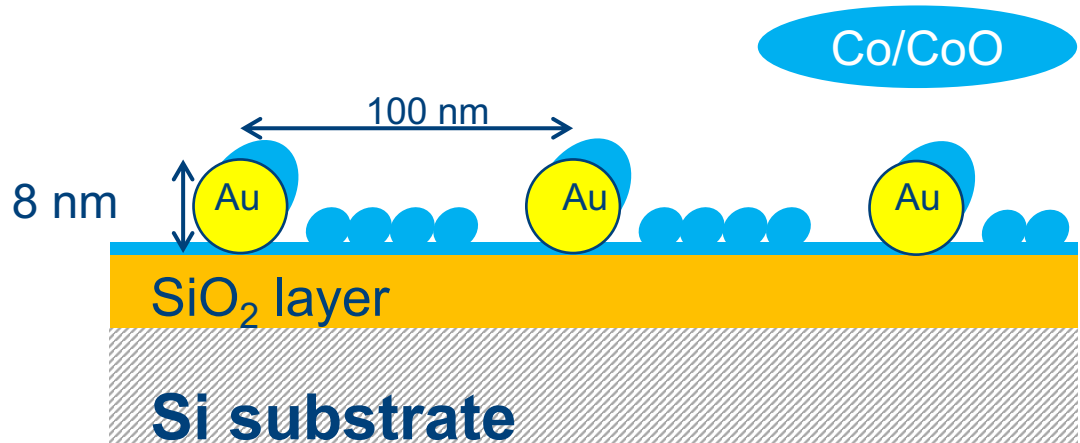
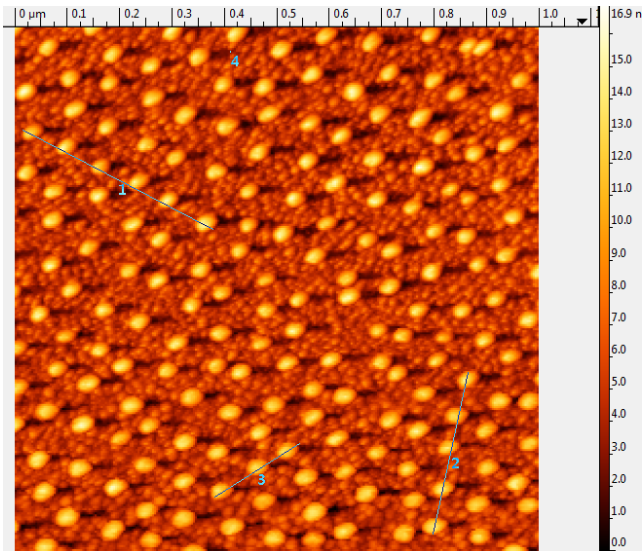
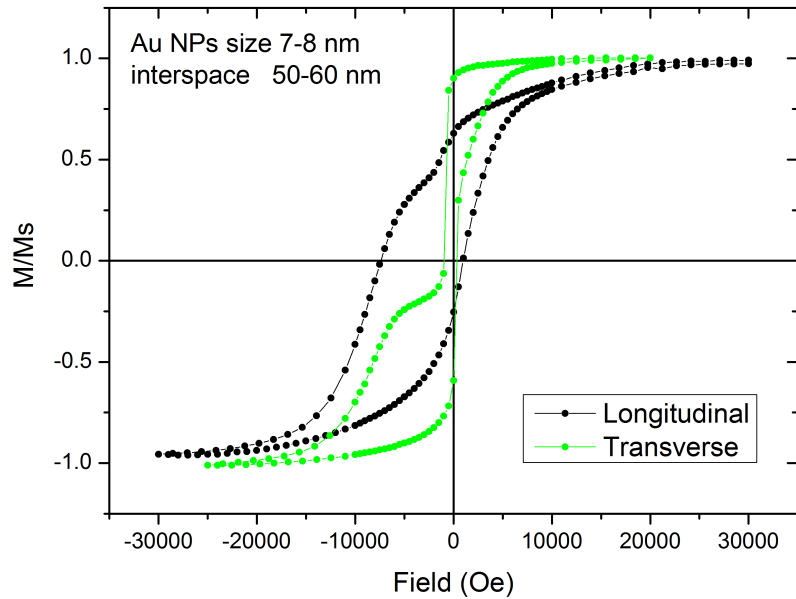
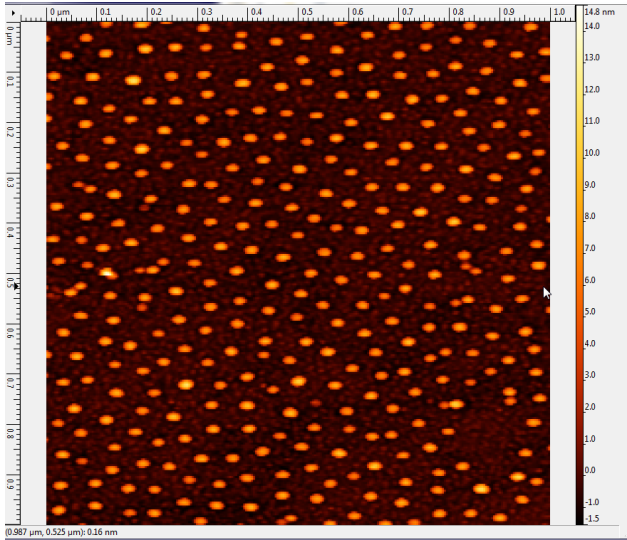
Domain walls in implanted areas (AMR)

Lateral pattern of domain walls (GMR) at boundaries between implanted and non-implanted areas





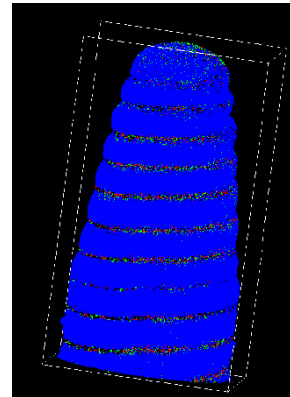
# Nanotemplate patterns



# The future: wish list

- magnetic fields with precise control
- 2-axis sample holder (azimuthal)
- combination with magnetotransport
- ability to apply electric fields
- 1K – 1000 K temperature range
- Easy switching (unpolarized/polarized, GISANS)
- measuring small samples (5 mm x 5 mm)
- 'plug and play' sample holders
- treatment of off-specular data
- further development of MBE/TEM (APT?)

[TbFe/Co] × 20



# Collaborators

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